Dual Bilateral Analog Switch / Digital Multiplexer

The NLX2G66 is a dual single pole, single throw (SPST) analog switch / digital multiplexer. This single supply voltage IC is designed with a sub-micron CMOS technology to provide low propagation delays (t_{nd}) and ON resistance (R_{ON}), while maintaining low power dissipation. This bi-lateral switch can be used with either analog or digital signals that may vary across the full power supply range from V_{CC} to GND.

Features

- Wide V_{CC} Operating Range: 1.65 V to 5.5 V
- OVT up to +5.5 V for Control Pin
- R_{ON}: Typically 5.5 Ω at V_{CC} = 4.5 V and I_S = 32 mA
- Rail-to-Rail Input/Output
- High On-Off Output Voltage Ratio
- High Degree of Linearity
- Ultra-Small Pb-Free, Halide-Free, RoHS-Compliant Packages
- ESD Performance: > 5000 V HBM, > 400 V MM

Typical Applications

• Cell Phones, PDAs, MP3 and other Portable Media Players

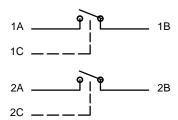


Figure 1. Analog Symbol

PIN ASSIGNMENTS

UDFN8	WLCSP8	Description
1	A1	1A
2	B1	1B
3	C1	2C
4	D1	GND
5	D2	2A
6	C2	2B
7	B2	1C
8	A2	V _{CC}

This document contains information on some products that are still under development. ON Semiconductor reserves the right to change or discontinue these products without notice.

1



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MARKING DIAGRAMS



UDFN8 **MU SUFFIX** CASE 517BZ





XX

UDFN8 **MU SUFFIX** CASE 517CA



= Specific Device Code = Date Code = Pb-Free Package

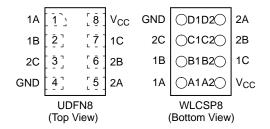


WLCSP8 **FC SUFFIX** CASE 567MR

XXXX **AYWW**

= Assembly Location = Year WW = Work Week

PIN ASSIGNMENTS



FUNCTION TABLE

Control Input (C)	Switch
L	OFF
Н	ON

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

Table 1. MAXIMUM RATINGS

Symbol	Rating		Value	Unit
V _{CC}	Positive DC Supply Voltage		-0.5 to +7.0	V
Vs	Switch Input / Output Voltage (F	Pins 1A, 1B, 2A and 2B)	-0.5 to + V _{CC} + 0.5	V
VI	Digital Control Input Voltage	(Pins 1C and 2C)	-0.5 to +7.0	V
I _{OK}	I/O port diode current		±50	mA
I _{IK}	Control input diode current		– 50	mA
I _{I/O}	Continuous DC Current Through Analog Switch		±100	mA
ΙL	Latch-up Current, (Above V _{CC} and below GND at 1	25°C)	±100	mA
Ts	Storage Temperature		-65 to +150	°C
V _{ESD}	ESD Withstand Voltage: Human Body Model Machine Model (MM)	` '	≥ 5000 > 400	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Table 2. RECOMMENDED OPERATING CONDITIONS

Symbol	Param	Parameter		Max	Unit
V _{CC}	Positive DC Supply Voltage		1.65	5.5	V
V _S	Switch Input / Output Voltage	(Pins 1A, 2A, 1B and 2B)	GND	V _{CC}	V
VI	Digital Control Input Voltage	(Pins 1C and 2C)	GND	5.5	V
T _A	Operating Temperature Range		-55	+125	°C
t _r , t _f	Input Transition Rise or Fall Time	V _{CC} = < 3.0 V	0	20	ns/V
	(ON/OFF Control Input)	$V_{CC} = \ge 3.0 \text{ V}$	0	10	

Table 3. ELECTRICAL CHARACTERISTICS

					Guarant	eed Limit		
				25	5°C	−55° to	125°C	
Symbol	Parameter	Condition	V _{CC}	Min	Max	Min	Max	Unit
V_{IH}	High-Level Input Voltage, Control Input		1.65 to 1.95			V _{CC} x 0.65		V
			2.3 to 5.5			V _{CC} x 0.7		
V _{IL}	Low-Level Input Voltage, Control Input		1.65 to 1.95				V _{CC} x 0.35	V
			2.3 to 5.5				V _{CC} x 0.30	
II	Input Leakage Current, Control Input	$V_{I} = V_{CC}$ or GND	5.5		±0.1		±1	μΑ
I _{S(ON)}	ON-State Switch Leakage Current	$V_{IS} = V_{CC}$ or GND, $V_{I} = V_{IH}$, $V_{OS} = Open$	5.5		±0.1		±1	μΑ
I _{S(OFF)}	OFF–State Switch Leakage Current	$\begin{aligned} & V_{IS} = V_{CC} \text{ and } V_{OS} = \\ & \text{GND, or } V_{IS} = \text{GND and} \\ & V_{OS} = V_{CC} \text{ GND, } V_{I} = V_{IL}, \end{aligned}$	5.5		±0.1		±1	μΑ
Icc	Quiescent Supply Current	$V_I = V_{CC}$ or GND	5.5		1.0		10	μΑ
ΔI_{CC}	Supply Current Change	$V_{I} = V_{CC} - 0.6$	5.5				500	μΑ
C _I	Control Input Capacitance		5				3.0	pF
C _{I/O(Off)}	Switch OFF Input / Output Capacitance	See Figure 3	5				6.0	pF
C _{I/O(On)}	Switch ON Input / Output Capacitance	See Figure 4	5				13	pF

Table 4. SWITCHING CHARACTERISTICS

				Guarante	ed Limit	
				–55° to	125°C	
Symbol	Parameter	Condition	V _{CC}	Min	Max	Unit
t _{PLH} , t _{PHL}	Propagation Delay,	$C_L = 30 \text{ pF}, R_L = 1 \text{ k}\Omega$	1.8		6.5	ns
	A to B, B to A		2.5		3.3	
		$C_L = 50 \text{ pF}, R_L = 500 \Omega$	3.3		2.5	
			5.0		2.2	
t _{EN}	Enable Time,	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8		10	ns
(t _{PZL} , t _{PZH})	C to Analog Output (A or B)	See Figure 6	2.5		6.5	
			3.3		5.5	
			5.0		4.9	
t _{DIS}	Disable Time,	$C_L = 50 \text{ pF}, R_L = 500 \Omega$	1.8		9.0	ns
(t _{PLZI} , t _{PHZ})	C to Analog Output (A or B)	See Figure 6	2.5		7.2]
			3.3		6.5	
			5.0		6.0	

Table 5. ANALOG SWITCH CHARACTERISTICS

					25°C	25°C -55° to 125°C	125°C	
Symbol Parameter		Conditions		V _{CC}	Тур	Min	Max	Unit
R _{ON}	On-Resistance	$V_{IS} = V_{CC}$ or GND,	I _S = 4 ma	1.65	12		30	Ω
		V _I = V _{IH} , See Figure 2	I _S = 8 ma	2.3	9		20	1
			I _S = 24 ma	3.0	7.5		15	1
			I _S = 32 ma	4.5	5.5		13	1
R _{ON(peak)}	Peak On–Resistance	$V_{IS} = GND \text{ to } V_{CC}; V_I = V_{IH},$	I _S = 4 ma	1.65	74.5		220	Ω
		See Figure 2	I _S = 8 ma	2.3	20		75	1
			I _S = 24 ma	3.0	11.5		25	1
			I _S = 32 ma	4.5	7.5		17	1
ΔR_{ON}	On-Resistance	$V_{IS} = GND$ to V_{CC} ; $V_I = V_{IH}$,	I _S = 4 ma	1.65			8.0	Ω
	Mismatch between Switches	See Figure 2	I _S = 8 ma	2.3			5.0	
			I _S = 24 ma	3.0			3.0	
			I _S = 32 ma	4.5			2.0	
BW	Bandwidth (f _{-3dB})	$R_L = 50 \Omega$, $C_L = 5 pF$,		1.65			> 270	MHz
		f _{IN} = Sine Wave See Figure 8		2.3			> 270	1
				3.0			> 270	
				4.5			> 270	

Table 5. ANALOG SWITCH CHARACTERISTICS (continued)

				25°C		
Symbol	Parameter	Conditions	v _{cc}	Тур	Unit	
ISO _{Off}	Off-Channel	$R_L = 600 \Omega$, $C_L = 50 pF$,	1.65	-70	dB	
	Feedthrough Isolation	f _{IN} = 1 MHz Sine Wave See Figure 9	2.3	-70		
			3.0	-70		
			4.5	-70		
		$R_L = 50 \Omega$, $C_L = 5 pF$,	1.65	-60		
		f _{IN} = 1 MHz Sine Wave See Figure 9	2.3	-60		
			3.0	-60		
			4.5	-60		
XTalk	Crosstalk Between Switches	$R_L = 600 \Omega$, $C_L = 50 pF$,	1.65	-100	dB	
		f _{IN} = 1 MHz Sine Wave See Figure 10	See Figure 10	2.3	-100	
			3.0	-100		
		4.5	4	4.5	-100	
		$R_L = 50 \Omega$, $C_L = 5 pF$,	1.65	-90		
		See Figure 10	f _{IN} = 1 MHz Sine Wave See Figure 10	2.3	-90	
			3.0	-90		
			4.5	-90		
	Feedthrough Noise,	$R_L = 600 \Omega$, $C_L = 50 pF$,	1.65	10	mV_{pp}	
	Control to Switch	$f_{IN} = 1$ MHz Square Wave, $t_r = t_f = 2$ ns, See Figure 11	2.3	10		
			3.0	3.0	10	
			4.5	15		
THD	Total Harmonic	$C_L = 50 \text{ pF}, R_L = 50 \Omega,$	2.3	0.025	%	
	Distortion	f _{IN} = 600 Hz to 20 KHz Sine Wave, See Figure 12	3.0	0.015		
			4.5	0.01		

Table 6. POWER DISSIPATION CHARACTERISTICS

				25°C	
Symbol	Parameter	Conditions	V _{CC}	Тур	Unit
C _{PD}	Power Dissipation Capacitance	f = 10 MHz	1.65	8.0	pF
	Capacitance		2.3	8.9	
			3.0	9.6	
			4.5	10.9	

Table 7. DEVICE ORDERING INFORMATION

Device Order Number	Package	Shipping [†]
NLX2G66DMUTAG	UDFN8-0.5P, 1.95 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel
NLX2G66DMUTCG	UDFN8-0.5P, 1.95 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel
NLX2G66MU3TCG (In Development)	UDFN8-0.35P, 1.45 mm x 1.0 mm (Pb-Free)	3000 / Tape & Reel
NLX2G66FCTAG	WLCSP8, 1.888 mm x 0.888 mm (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

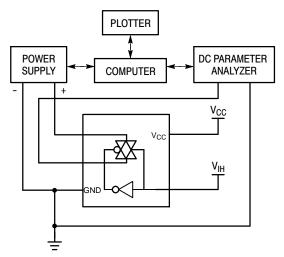


Figure 2. On Resistance Test Set-Up

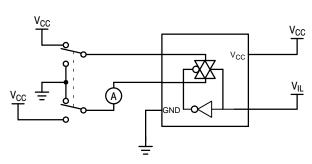


Figure 3. Maximum Off-Channel Leakage Current Test Set-Up

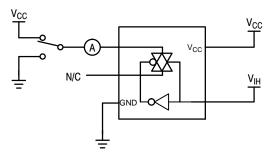


Figure 4. Maximum On-Channel Leakage Current Test Set-Up

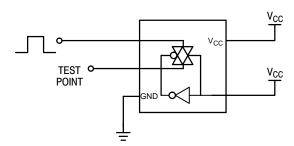


Figure 5. Propagation Delay Test Set-Up

Switch to Position 2 when testing t_{PLZ} and t_{PZL} Switch to Position 1 when testing t_{PHZ} and t_{PZH}

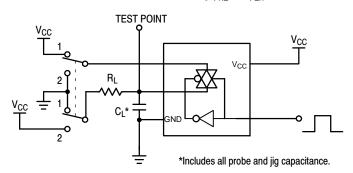


Figure 6. Propagation Delay Output Enable/Disable Test Set-Up

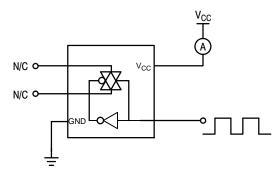
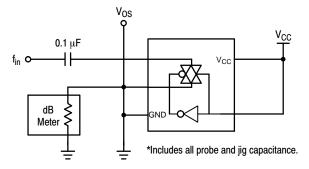


Figure 7. Power Dissipation Capacitance Test Set-Up



 $f_{in} \stackrel{\text{V}_{IS}}{\longrightarrow} V_{OS} \stackrel{\text{V}_{CC}}{\longrightarrow} V_{CC}$

Figure 8. Maximum On-Channel Bandwidth
Test Set-Up

Figure 9. Off-Channel Feedthrough Isolation
Test Set-Up

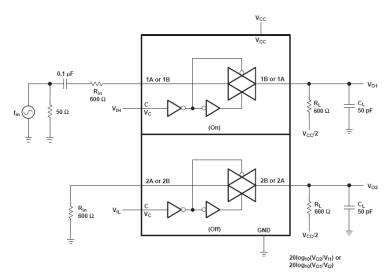


Figure 10. Crosstalk (between Switches)

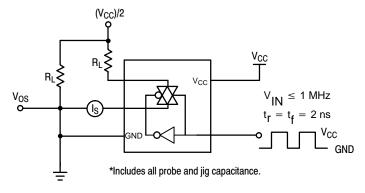


Figure 11. Feedthrough Noise, ON/OFF Control to Analog Out, Test Set-Up

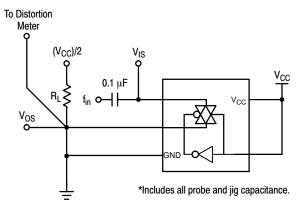


Figure 12. Total Harmonic Distortion Test Set-Up

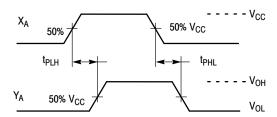


Figure 13. Propagation Delay, Analog In to Analog Out Waveforms

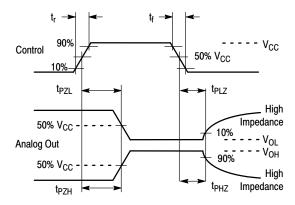
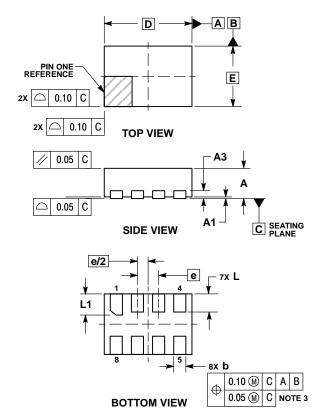


Figure 14. Propagation Delay, ON/OFF Control

PACKAGE DIMENSIONS

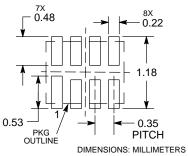
UDFN8 1.45x1.0, 0.35P CASE 517BZ ISSUE O



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS			
DIM	MIN	MAX		
Α	0.45	0.55		
A1	0.00	0.05		
A3	0.13 REF			
b	0.15	0.25		
D	1.45	BSC		
E	1.00	BSC		
е	0.35	BSC		
L	0.25	0.35		
L1	0.30	0.40		

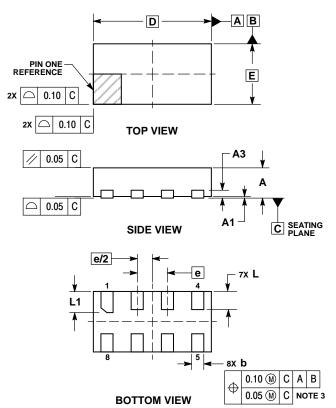
RECOMMENDED SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

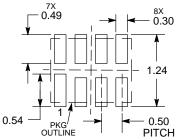
UDFN8 1.95x1.0, 0.5P CASE 517CA ISSUE O



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
 4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS		
DIM	MIN MAX		
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.15	0.25	
D	1.95	BSC	
Е	1.00	BSC	
е	0.50 BSC		
L	0.25	0.35	
L1	0.30	0.40	

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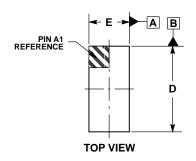


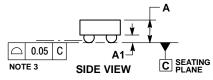
DIMENSIONS: MILLIMETERS

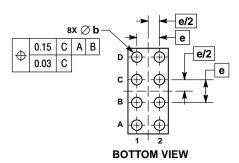
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PACKAGE DIMENSIONS

WLCSP8, 1.888x0.888 CASE 567MR **ISSUE O**





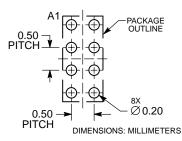


NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. COPLANARITY APPLIES TO SPHERICAL CROWNS OF SOLDER BALLS.

	MILLIMETERS	
DIM	MIN	MAX
Α	i	0.50
A1	0.15	0.19
b	0.21	0.25
D	1.858	1.918
E	0.858	0.918
е	0.50 BSC	

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